





SN74LVC00A-Q1 SCAS703D - SEPTEMBER 2003 - REVISED MAY 2024

SN74LVC00A-Q1 Automotive Quadruple 2-Input Positive-NAND Gate

1 Features

Texas

- Qualified for automotive applications
- Operates from 2V to 3.6V
- Inputs accept voltages to 5.5V
- Max t_{pd} of 4.3ns at 3.3V

INSTRUMENTS

- Typical V_{OLP} (output ground bounce) < 0.8V at V_{CC} = 3.3V, T_A = 25°C
- Typical V_{OHV} (output V_{OH} undershoot) > 2V at V_{CC} = 3.3V, T_A = 25°C

2 Description

The SN74LVC00A-Q1 quadruple 2-input positive-NAND gate is designed for 2.7V to 3.6V V_{CC} operation.

The device performs the Boolean function $Y = \overline{A \cdot B}$ or $Y = \overline{A} + \overline{B}$ in positive logic.

Inputs can be driven from either 3.3V or 5V devices. This feature allows the use of this device as a translator in a mixed 3.3V/5V system environment.

Package Information					
MBER	PACKAGE ⁽¹⁾	PACKAGE SIZE ⁽²⁾	BODY SIZE ⁽³⁾		
	DOA ANOTH AN	0 05	0 05		

PARTNUMBER	PACKAGE	PACKAGE SIZE	BODY SIZE
	BQA (WQFN, 14)	3mm × 2.5mm	3mm × 2.5mm
SN74LVC00A-Q1	D (SOIC, 14)	8.65mm × 6mm	8.65mm × 3.9mm
	PW (SOP, 14)	5mm × 6.4mm	5mm × 4.4mm

For more information, see Section 10. (1)

(2) The package size (length × width) is a nominal value and includes pins, where applicable.

(3) The body size (length × width) is a nominal value and does not include pins.



Logic Diagram, Each Gate (Positive Logic)





Table of Contents

1 Features 2 Description	
3 Pin Configuration and Functions	
4 Specifications	4
4.1 Absolute Maximum Ratings	
4.2 ESD Ratings	4
4.3 Recommended Operating Conditions	4
4.4 Thermal Information	4
4.5 Electrical Characteristics	<mark>5</mark>
4.6 Switching Characteristics	<mark>5</mark>
4.7 Operating Characteristics	5
5 Parameter Measurement Information	
6 Detailed Description	7
6.1 Functional Block Diagram	7

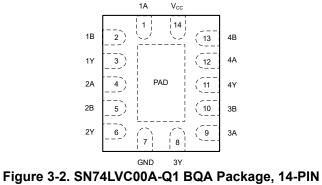
6.2 Device Functional Modes	7
7 Application and Implementation	8
7.1 Power Supply Recommendations	8
7.2 Layout	
8 Device and Documentation Support	
8.1 Documentation Support.	
8.2 Receiving Notification of Documentation Updates	
8.3 Support Resources	
8.4 Trademarks	
8.5 Electrostatic Discharge Caution	
8.6 Glossary	
9 Revision History	
10 Mechanical, Packaging, and Orderable	
Information	. 10



3 Pin Configuration and Functions

1A [1	\cup	14] V _{CC}] 4B
1B [2		13] 4B
1Y [3] 4A
2A [4		11] 4Y
4	5		10	
2Y 🛛	6		9] 3A
GND	7		8] 3Y

Figure 3-1. SN74LVC00A-Q1 D or PW Package, 14-
Pin SOIC or TSSOP (Top View)



WQFN (Top View)

PIN			DESCRIPTION		
NAME	NO.		DESCRIPTION		
1A	1	I	Channel 1, Input A		
1B	2	I	Channel 1, Input B		
1Y	3	0	Channel 1, Output Y		
2A	4	I	Channel 2, Input A		
2B	5	I	Channel 2, Input B		
2Y	6	0	Channel 2, Output Y		
GND	7	_	Ground		
3Y	8	0	Channel 3, Output Y		
3A	9	I	Channel 3, Input A		
3B	10	I	Channel 3, Input B		
4Y	11	0	Channel 4, Output Y		
4A	12	I	Channel 4, Input A		
4B	13	I	Channel 4, Input B		
V _{CC}	14	-	Positive Supply		
Thermal Info	rmation	_	The thermal pad can be connected to GND or left floating. Do not connect to any other signal or supply.		

Table 3-1. Pin Functions

(1) Signal Types: I = Input, O = Output, I/O = Input or Output, P = Power Supply, G = Ground.



4 Specifications

4.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	6.5	V
VI	Input voltage range ⁽¹⁾		-0.5	6.5	V
Vo	Output voltage range ⁽¹⁾ ⁽²⁾		-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V ₁ < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
lo	Continuous output current			±50	mA
	Continuous current through V_{CC} or GND			±100	mA
T _{stg}	Storage temperature range		-65	150	°C

(1) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

(2) The value of V_{CC} is provided in the recommended operating conditions table.

4.2 ESD Ratings

			VALUE	UNIT
V (ESD)	Electrostatic discharge	Human body model (HBM), per AEC Q100-002 ⁽¹⁾	±2000	V

(1) AEC Q100-002 indicates that HBM stressing must be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

4.3 Recommended Operating Conditions

			MIN	MAX	UNIT
V	Supply voltage	Operating	2	3.6	V
V _{cc}	Supply voltage	Data retention only	1.5		v
V _{IH}	High-level input voltage	V _{CC} = 2.7V to 3.6V	2		V
V _{IL}	Low-level input voltage	V _{CC} = 2.7V to 3.6V		0.8	V
VI	Input voltage		0	5.5	V
Vo	Output voltage		0	V_{CC}	V
	High-level output current	V _{CC} = 2.7V		-12	mA
ЮН	nigh-level output current	V _{CC} = 3V		-24	ШA
	Low lovel output ourrent	V _{CC} = 2.7V		12	mA
I _{OL}	Low-level output current V _{CC} = 3V			24	ШA
T _A	Operating free-air temperature		-40	125	°C

4.4 Thermal Information

			SN74LVC00A-Q1		
		BQA	D	PW (TSSOP)	UNIT
		14 PINS	14 PINS	14 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	102.3	127.8	150.8	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC package thermal metrics* application report.



4.5 Electrical Characteristics

PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP ⁽¹⁾ MAX	UNIT
	I _{OH} = -100μA	2.7V to 3.6V	V _{CC} - 0.2		
Maria	I _{OH} = -12mA	2.7V	2.2		V
V _{OH}	10H = -1210A	3V	2.4		v
	$I_{OH} = -24mA$	3V	2.2		
	I _{OL} = 100μA	2.7V to 3.6V		0.2	
V _{OL}	I _{OL} = 12mA	2.7V		0.4	V
	I _{OL} = 24mA	3V		0.55	
l _l	V _I = 5.5V or GND	3.6V		±5	μA
I _{CC}	$V_{I} = V_{CC} \text{ or } GND, \qquad I_{O} = 0$	3.6V		10	μA
ΔI _{CC}	One input at V_{CC} – 0.6V, Other inputs at V_{CC} or GND	2.7V to 3.6V		500	μA
C _i	$V_{I} = V_{CC}$ or GND	3.3V		5	pF

over recommended operating free-air temperature range (unless otherwise noted)

(1) All typical values are at V_{CC} = 3.3 V, T_A = 25°C.

4.6 Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	PARAMETER FROM (INPUT)		V _{cc} =	2.7V	V _{CC} = 3.3V ± 0.3V		UNIT
		(OUTPUT)	MIN	MAX	MIN	MAX	
t _{pd}	A or B	Y		5.1	1	4.3	ns

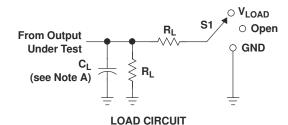
4.7 Operating Characteristics

T_A = 25°C

	PARAMETER	TEST	V_{CC} = 2.5V	$V_{CC} = 3.3V$	UNIT	
FARAIMETER		CONDITIONS	ТҮР	TYP	UNIT	
C _{pd}	Power dissipation capacitance per gate	f = 10MHz	18	19	pF	

٧ı

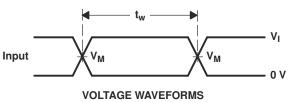
5 Parameter Measurement Information

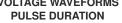


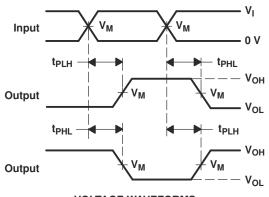
TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	V _{LOAD}
t _{PHZ} /t _{PZH}	GND

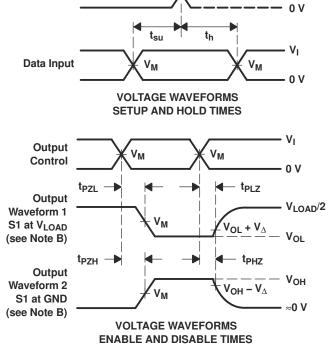
	INPUTS		N	V	•	-	V
V _{CC}	VI	t _r /t _f	VM	V _{LOAD}	CL	RL	V_{Δ}
1.8 V \pm 0.15 V	V _{CC}	≤2 ns	V _{CC} /2	$2 \times V_{CC}$	30 pF	1 k Ω	0.15 V
$\textbf{2.5 V} \pm \textbf{0.2 V}$	V _{CC}	≤2 ns	V _{CC} /2	$2 \times V_{CC}$	30 pF	500 Ω	0.15 V
2.7 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
3.3 V \pm 0.3 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V

Timing Input









LOW- AND HIGH-LEVEL ENABLING

V_M

VOLTAGE WAVEFORMS PROPAGATION DELAY TIMES INVERTING AND NONINVERTING OUTPUTS

NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω .
- $\mathsf{D}.\;\;$ The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.

Figure 5-1. Load Circuit and Voltage Waveforms



6 Detailed Description

6.1 Functional Block Diagram



Figure 6-1. Logic Diagram, Each Gate (Positive Logic)

6.2 Device Functional Modes

Function Table
(Faals Oata)

	(Each Gate)										
INF	PUTS	OUTPUT									
Α	В	Y									
н	Н	L									
L	Х	н									
X	L	н									



7 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

7.1 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. A 0.1-µF capacitor is recommended for this device. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. The 0.1-µF and 1-µF capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results, as shown in given example layout image.

7.2 Layout

7.2.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices inputs must never be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or V_{CC} , whichever makes more sense for the logic function or is more convenient.

7.2.2 Layout Example

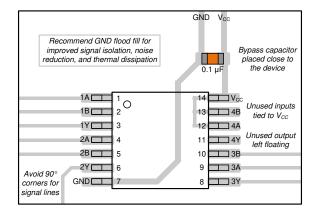


Figure 7-1. Example Layout for the SN74LVC00A-Q1



8 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

8.1 Documentation Support

8.1.1 Related Documentation

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY						
SN74LVC00A-Q1	Click here	Click here	Click here	Click here	Click here						

Table 8-1. Related Links

8.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

8.4 Trademarks

TI E2E[™] is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

8.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.6 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

С	hanges from Revision C (March 2024) to Revision D (May 2024)	Page
•	Updated RθJA values: PW = 113 to 150.8, all values in °C/W	4

Changes from Revision B (February 2008) to Revision C (March 2024)	Page
--	------

 Added Package Information table, Pin Functions table, ESD Ratings table, Thermal Information table, Device Functional Modes, Application and Implementation section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section



•	Added BQA package to Package Information table, Pin Configuration and Functions section, and Thermal
	Information table
•	Updated RθJA values: D = 86 to 127.8, all values in °C/W4

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/	Lead finish/ MSL rating/		Part marking
	(1)	(2)			(3)	Ball material	Peak reflow		(6)
						(4)	(5)		
SN74LVC00ADRQ1	Active	Production	SOIC (D) 14	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC00AQ
SN74LVC00ADRQ1.A	Active	Production	SOIC (D) 14	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC00AQ
SN74LVC00AQPWRG4Q1	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC00AQ
SN74LVC00AQPWRG4Q1.B	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC00AQ
SN74LVC00AQPWRQ1	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 125	LVC00AQ
SN74LVC00AQPWRQ1.A	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 125	LVC00AQ
SN74LVC00AQPWRQ1.B	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 125	LVC00AQ
SN74LVC00AWBQARQ1	Active	Production	WQFN (BQA) 14	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC00Q
SN74LVC00AWBQARQ1.A	Active	Production	WQFN (BQA) 14	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC00Q

⁽¹⁾ **Status:** For more details on status, see our product life cycle.

(2) Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative



www.ti.com

PACKAGE OPTION ADDENDUM

23-May-2025

and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN74LVC00A-Q1 :

- Catalog : SN74LVC00A
- Enhanced Product : SN74LVC00A-EP
- Military : SN54LVC00A
- NOTE: Qualified Version Definitions:
 - Catalog TI's standard catalog product
 - Enhanced Product Supports Defense, Aerospace and Medical Applications
 - Military QML certified for Military and Defense Applications



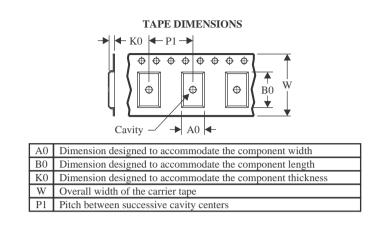
Texas

*All dimensions are nominal

STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC00ADRQ1	SOIC	D	14	3000	330.0	12.4	3.75	3.75	1.15	8.0	12.0	Q1
SN74LVC00AQPWRG4Q1	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC00AQPWRQ1	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC00AWBQARQ1	WQFN	BQA	14	3000	180.0	12.4	2.8	3.3	1.1	4.0	12.0	Q1



www.ti.com

PACKAGE MATERIALS INFORMATION

24-Jul-2025



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC00ADRQ1	SOIC	D	14	3000	340.5	336.1	32.0
SN74LVC00AQPWRG4Q1	TSSOP	PW	14	2000	353.0	353.0	32.0
SN74LVC00AQPWRQ1	TSSOP	PW	14	2000	353.0	353.0	32.0
SN74LVC00AWBQARQ1	WQFN	BQA	14	3000	210.0	185.0	35.0

D0014A



PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
- 5. Reference JEDEC registration MS-012, variation AB.



D0014A

EXAMPLE BOARD LAYOUT

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



D0014A

EXAMPLE STENCIL DESIGN

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



BQA 14

2.5 x 3, 0.5 mm pitch

GENERIC PACKAGE VIEW

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





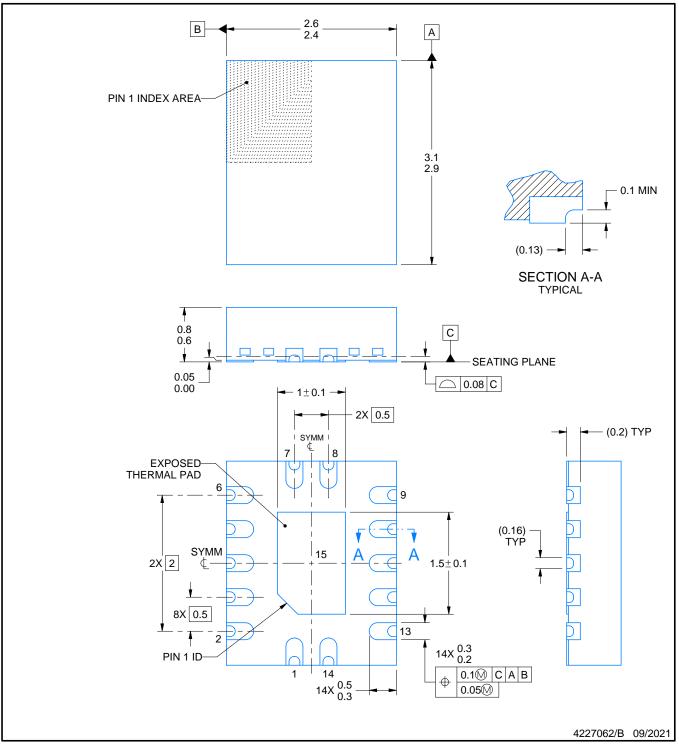
BQA0014B



PACKAGE OUTLINE

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

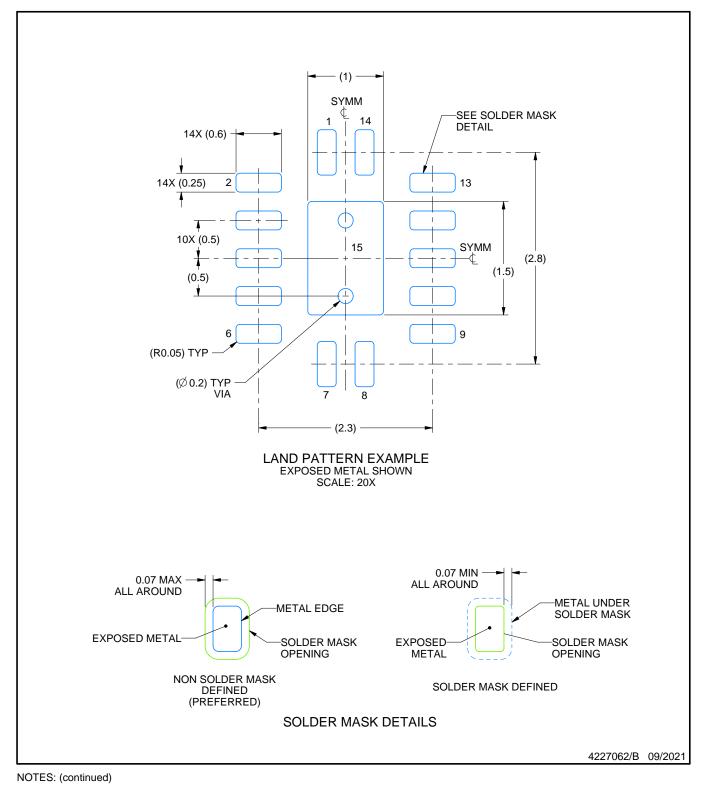


BQA0014B

EXAMPLE BOARD LAYOUT

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



 This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

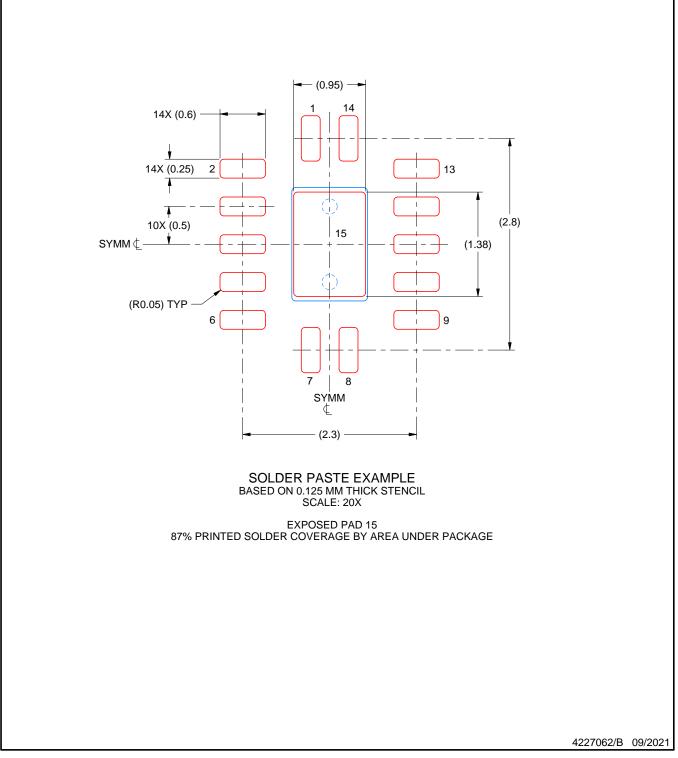


BQA0014B

EXAMPLE STENCIL DESIGN

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



PW0014A



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



PW0014A

EXAMPLE BOARD LAYOUT

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PW0014A

EXAMPLE STENCIL DESIGN

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2025, Texas Instruments Incorporated